

09/936040

PATENT APPLICATIONIN THE UNITED STATES PATENT AND TRADEMARK OFFICE *S. S.**AP7/1  
3-14-02*

In re the Application of

Ichio YUDASAKA, Mitsutoshi MIYASAKA,  
Piero MIGLIORATO

Application No.: U.S. National Stage of PCT/GB01/00007

Filed: September 7, 2001

Docket No.: 110554

For: A THIN FILM TRANSISTOR AND A METHOD FOR MANUFACTURING  
THEREOFPRELIMINARY AMENDMENTDirector of the U.S. Patent and Trademark Office  
Washington, D. C. 20231

Sir:

Prior to initial examination, please amend the above-identified application as follows:

~~IN THE CLAIMS:~~

Please replace claims 4 and 5 as follows:

4. (Amended) The thin film transistor according to Claim 1, wherein the regions, among said channel regions, in which said recombination centers are concentrated have different film thickness compared to other regions.  
*a)*

5. (Amended) The thin film transistor according to Claim 1, wherein the regions, among said channel regions, in which said recombination centers are concentrated have different surface positions compared to other regions.

Please add new claims 13-16 as follows: